Supplementary Information

Control of oxygen vacancies in ZnO nanorods by annealing and their influence on ZnO/PEDOT:PSS diode behaviour

Ying Tu\textsuperscript{a}, Shuqun Chen\textsuperscript{b}, Xuan Li\textsuperscript{a}, Jelena Gorbaciova\textsuperscript{c}, William P. Gillin\textsuperscript{c}, Steffi Krause\textsuperscript{a}, and Joe Briscoe\textsuperscript{a,*}

\textsuperscript{a} Materials Research Institute and School of Engineering and Materials Science, Queen Mary University of London, Mile End Road, London, E1 4NS, UK. E-mail:j.briscoe@qmul.ac.uk

\textsuperscript{b} Key Laboratory of Advanced Functional Materials, School of Materials and Engineering, Beijing University of Technology, Beijing, 100124, China

\textsuperscript{c} Materials Research Institute and School of Physics and Astronomy, Queen Mary University of London, Mile End Road, London, E1 4NS, UK

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\textbf{Figure S1} SEM image of the ZnO/PEDOT:PSS interface with ZnO partially removed. The holes in the PEDOT:PSS layer originated from the tips of the ZnO nanorods which penetrated inside the layer.
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